

Si photodiodes

S12698 series

High UV resistance, photodiodes for UV monitor

The S12698 series are Si photodiodes that have achieved high reliability for monitoring ultraviolet light by employing a structure that does not use resin. They exhibit low sensitivity deterioration under UV light irradiation and are suitable for applications such as monitoring intense UV light sources.

Features

- With UV glass window (hermetically sealed)
- High sensitivity in UV region
- High reliability for monitoring UV light irradiation
- Resin material not used

Applications

- Power monitor for UV light sources
- Analytical instrument
- **Optical measurement equipment**

Structure / Absolute maximum ratings

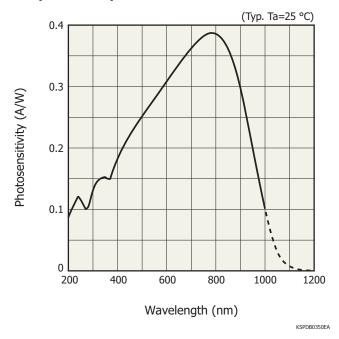
Type no.	Window material	Package		Effortivo	Absolute maximum ratings			
			Photosensitive area size	Effective photosensitive area	Reverse voltage VR max (V)	Operating temperature Topr	Storage temperature Tsto	
			(mm)	(mm²)		Topr (°C)	Tstg (°C)	
S12698		TO-18	1.1 × 1.1	1.2				
S12698-01	UV glass	TO-5	2.4 × 2.4	5.8	5	-40 to +100	-55 to +125	
S12698-02		TO-8	5.8 × 5.8	33.6				

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

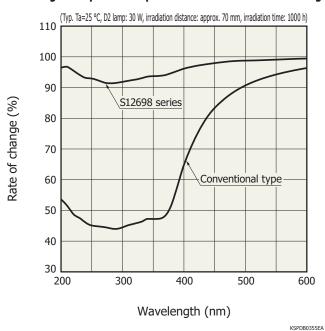
■ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

Type no.	Spectral response range	Peak sensitivity wavelength λp	Photosensitivity	I	circuit rent sc 0 lx Typ.	Dark current ID VR=10 mV max.	Temp. coefficient of ID TCID	Rise time tr $VR=0 V$ $RL=1 k\Omega$ $\lambda=655 nm$	Terminal capacitance Ct VR=0 V f=10 kHz	Shunt resistance Rsh max.	Noise equivalent power NEP
	(nm)	(nm)	(A/W)	(µA)	(µA)	(pA)	(times/°C)	(µs)	(pF)	(GΩ)	(W/Hz ^{1/2})
S12698				0.6	0.8	10		0.1	25	1	1×10^{-14}
S12698-01	190 to 1000	800	0.38	1.7	2.5	30	1.12	0.5	230	0.3	2×10^{-14}
S12698-02				12	18	100		1.5	700	0.1	3.5×10^{-14}

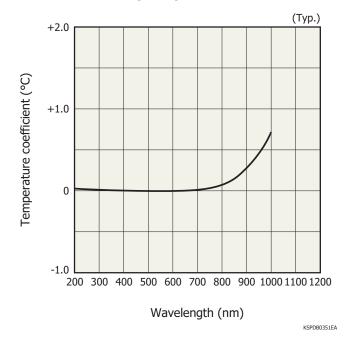
Spectral response



Changes in spectral response after irradiated with UV light

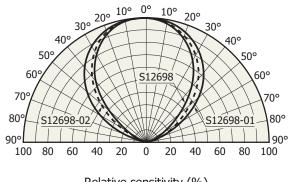


Photosensitivity temperature characteristics



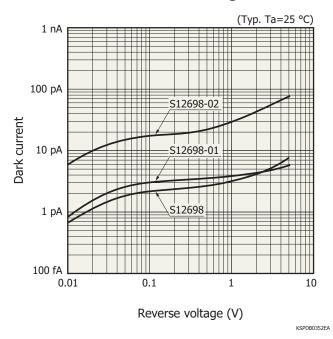
Directivity

(Typ. Ta=25 °C, light source: tungsten lamp)

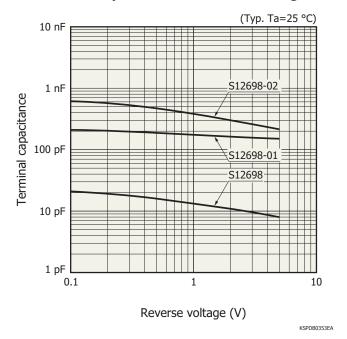


Relative sensitivity (%)

Dark current vs. reverse voltage

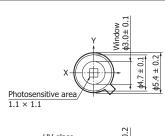


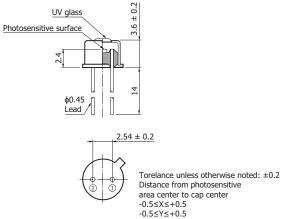
Terminal capacitance vs. reverse voltage



Dimensional outlines (unit: mm)





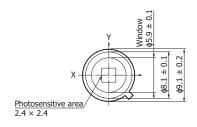


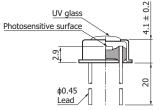


The UV glass window may extend a maximum of 0.2 mm beyond the upper surface of the cap.

KSPDA0209EA

S12698-01







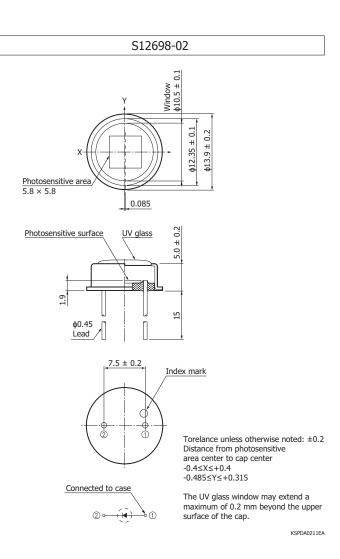
Torelance unless otherwise noted: ± 0.2 Distance from photosensitive area center to cap center $-0.5 \le X \le +0.5$ $-0.5 \le Y \le +0.5$



The UV glass window may extend a maximum of 0.2 mm beyond the upper surface of the cap.

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Precautions against UV light exposure

· When UV light irradiation is applied, the product characteristics may degrade. Such examples include degradation of the product's UV sensitivity and increase in dark current. This phenomenon varies depending on the irradiation level, irradiation intensity, usage time, and ambient environment and also varies depending on the product model. Before employing the product, we recommend that you check the tolerance under the ultraviolet light environment that the product will be used in.



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Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- · Metal, ceramic, plastic package products
- Technical information
- · Si photodiode / Application circuit example

Information described in this material is current as of November, 2015.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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5